

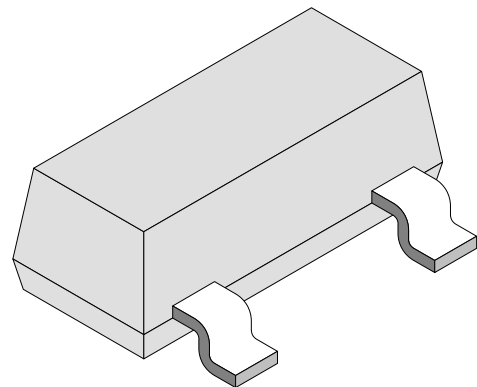
## SMD LED in Tinted Diffused SOT23 Package

Color	Type	Technology	Angle of Half Intensity $\pm\varphi$
High efficiency red	TLMR2200	GaAsP on GaP	70°
Yellow	TLMY2200	GaAsP on GaP	
Green	TLMG2200	GaP on GaP	

### Description

The TLM.2200 series is suitable for very flat backlighting applications like key pad illumination or indicator displays.

The wide viewing angle allows users to assemble LEDs with uniform appearance.



94 8550

### Features

- Standard SOT 23 package
- Especially for surface mounting on printed boards
- Luminous intensity categorized
- Yellow and green color categorized
- Small mechanical tolerances
- Suitable for DC and high peak current

### Applications

Status lights  
OFF / ON indicator  
Background illumination  
Readout lights  
Maintenance lights  
Legend light  
Backlighting

## TLM.2200

### Absolute Maximum Ratings

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

**TLMR2200 , TLMY2200 , TLMG2200**

Parameter	Test Conditions	Type	Symbol	Value	Unit
Reverse voltage			$V_R$	6	V
DC forward current			$I_F$	23	mA
Surge forward current	$t_p \leq 10 \mu\text{s}$		$I_{FSM}$	1	A
Power dissipation	$T_{amb} \leq 30^{\circ}\text{C}$		$P_V$	70	mW
Junction temperature			$T_j$	100	$^{\circ}\text{C}$
Storage temperature range			$T_{stg}$	-55 to +100	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5 \text{ s}$		$T_{sd}$	240	$^{\circ}\text{C}$
Thermal resistance junction/ambient			$R_{thJA}$	1000	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified

**High efficiency red (TLMR2200 )**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$		$I_V$	1	1.6		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	612		625	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		635		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\varphi$		$\pm 70$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		50		pF

**Yellow (TLMY2200 )**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$		$I_V$	0.4	0.63		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	581		594	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		585		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\varphi$		$\pm 70$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		50		pF

**Green (TLMG2200)**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous intensity	$I_F = 10 \text{ mA}$		$I_V$	0.4	0.63		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	562		575	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		565		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 70$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		50		pF

**Typical Characteristics** ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified)

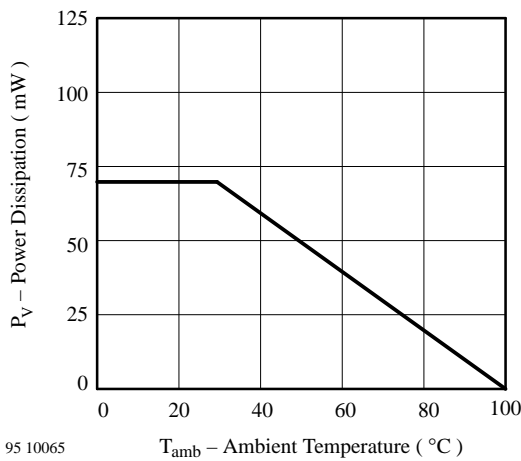


Figure 1. Power Dissipation vs. Ambient Temperature

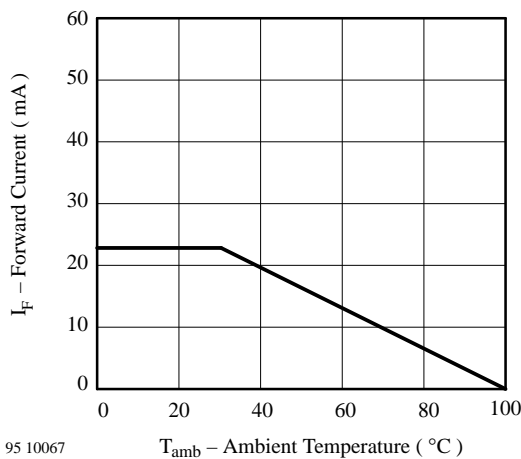


Figure 2. Forward Current vs. Ambient Temperature

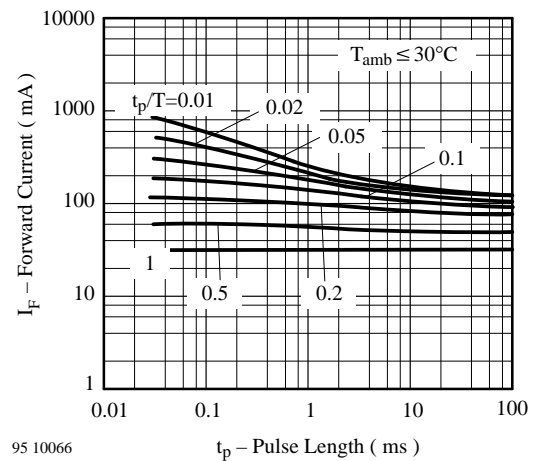


Figure 3. Forward Current vs. Pulse Length

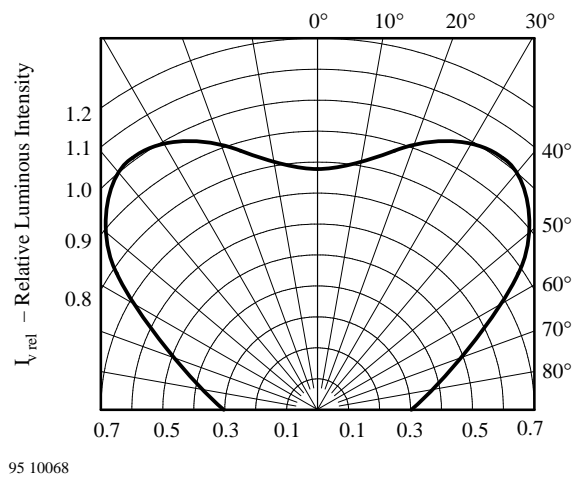


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

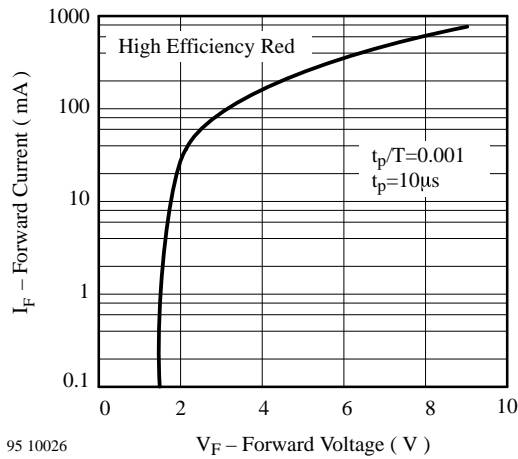


Figure 5. Forward Current vs. Forward Voltage

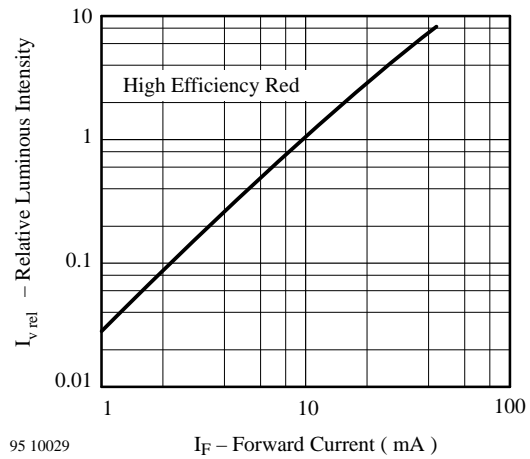


Figure 8. Relative Luminous Intensity vs. Forward Current

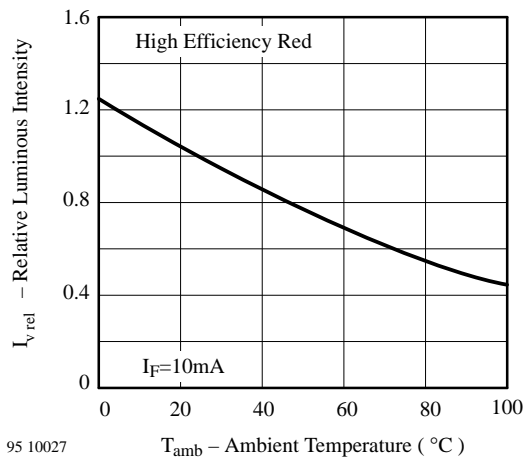


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

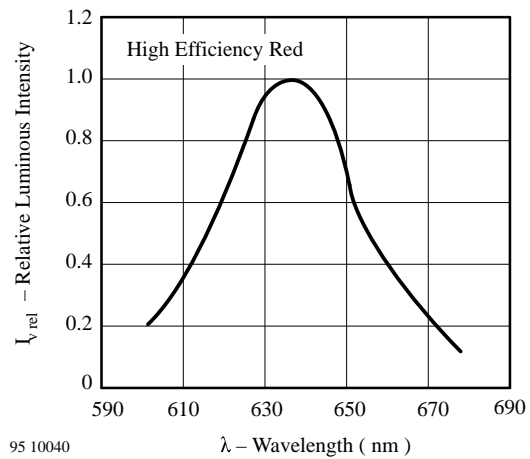


Figure 9. Relative Luminous Intensity vs. Wavelength

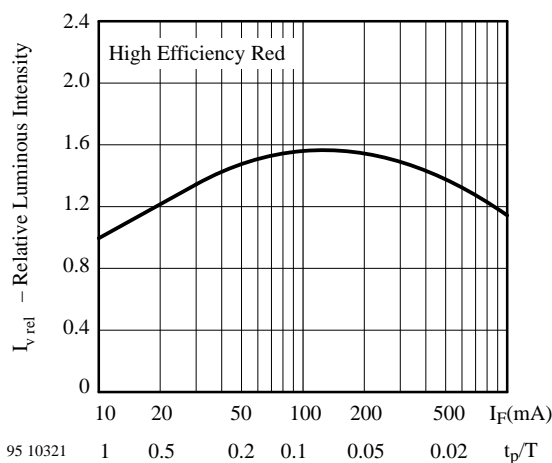


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

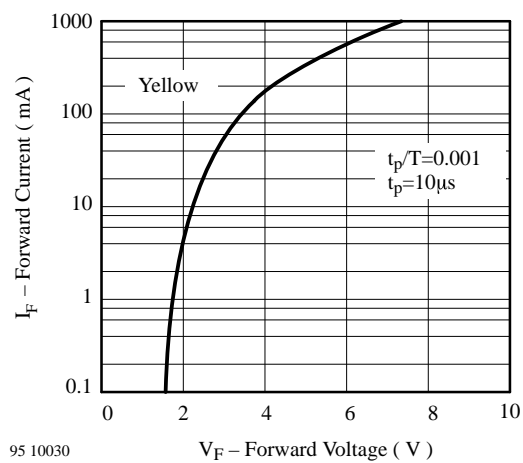


Figure 10. Forward Current vs. Forward Voltage

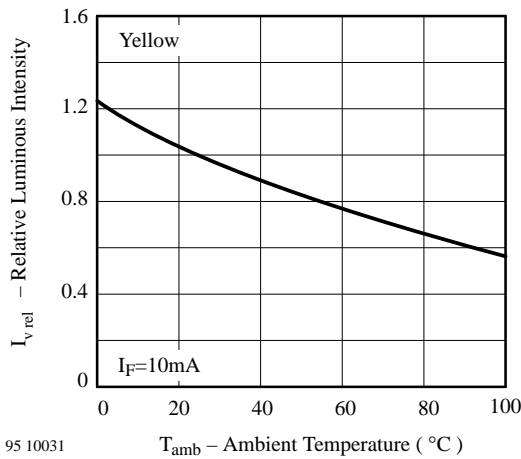


Figure 11. Rel. Luminous Intensity vs. Ambient Temperature

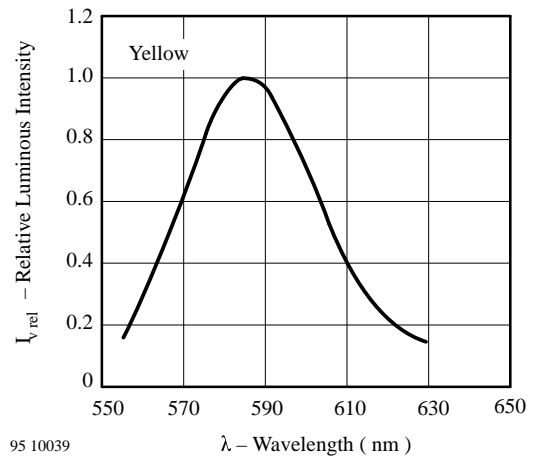


Figure 14. Relative Luminous Intensity vs. Wavelength

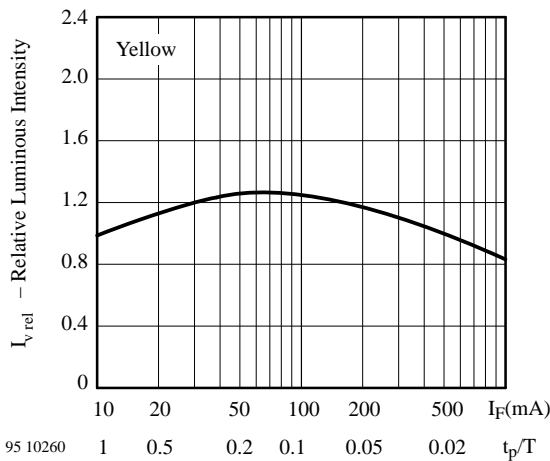


Figure 12. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

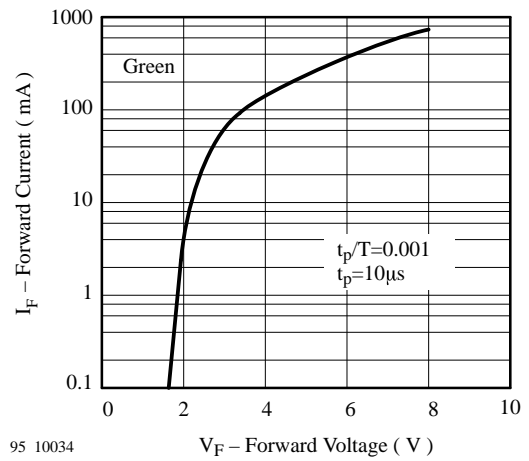


Figure 15. Forward Current vs. Forward Voltage

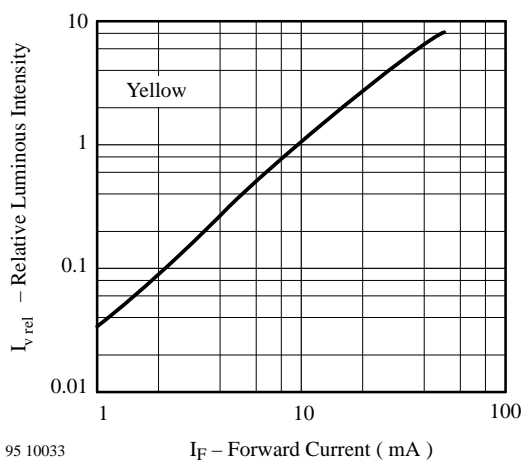


Figure 13. Relative Luminous Intensity vs. Forward Current

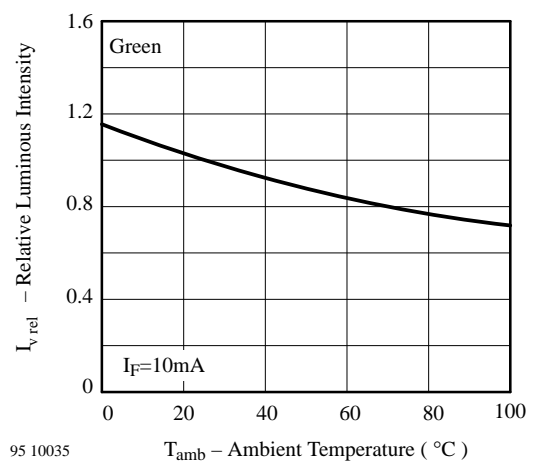


Figure 16. Rel. Luminous Intensity vs. Ambient Temperature

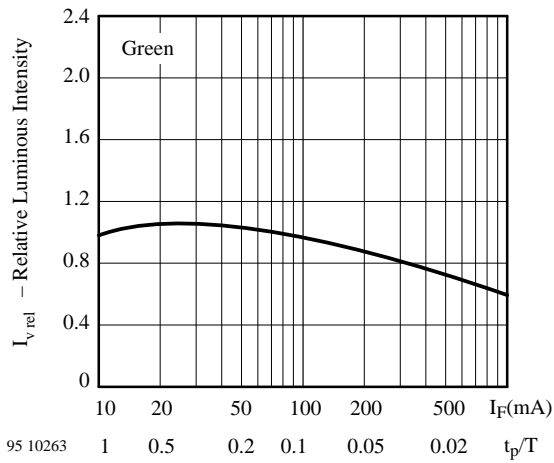


Figure 17. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

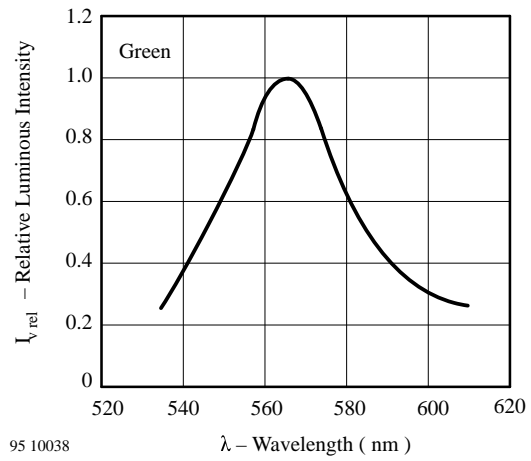


Figure 19. Relative Luminous Intensity vs. Wavelength

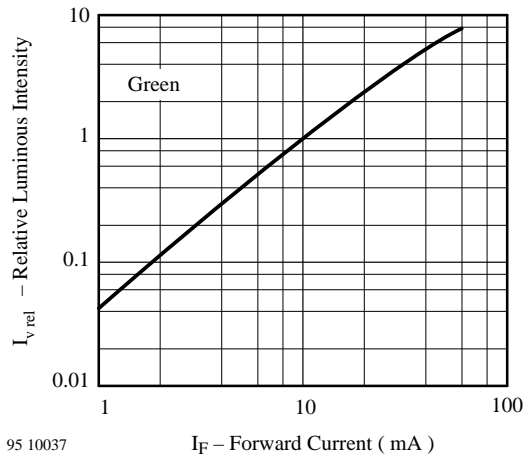
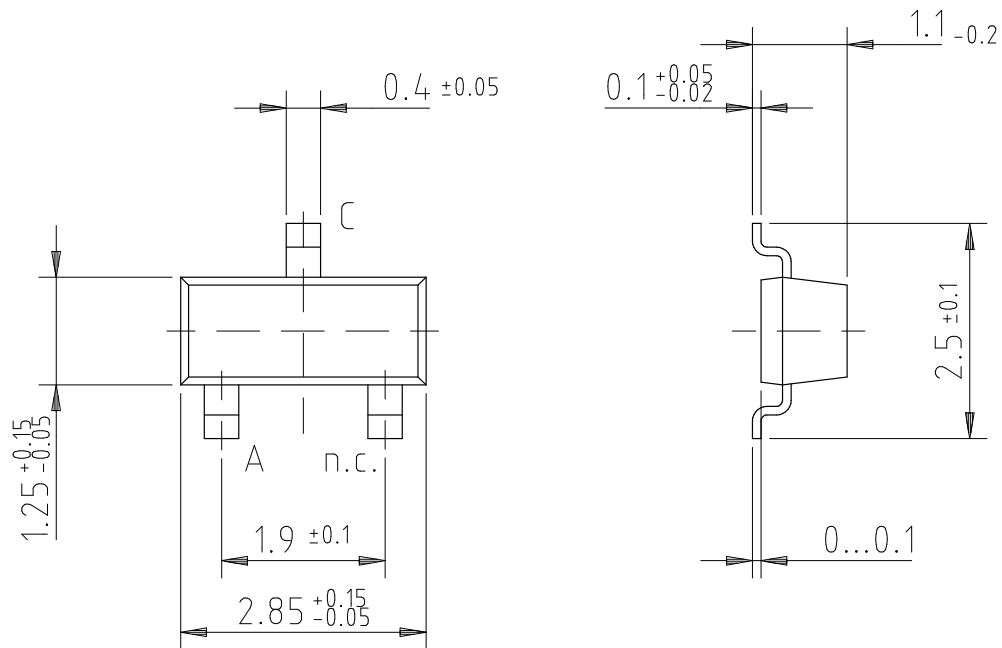
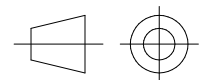


Figure 18. Relative Luminous Intensity vs. Forward Current

## Dimensions in mm



95 11348



technical drawings  
according to DIN  
specifications

## Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany  
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423